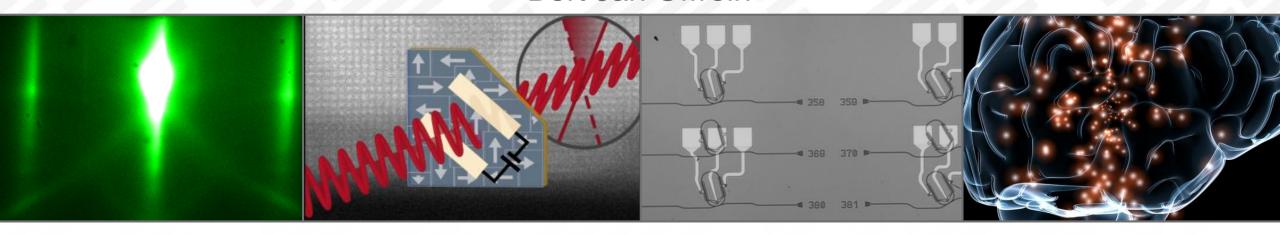
# Advancing silicon photonics for traditional and novel computing paradigms

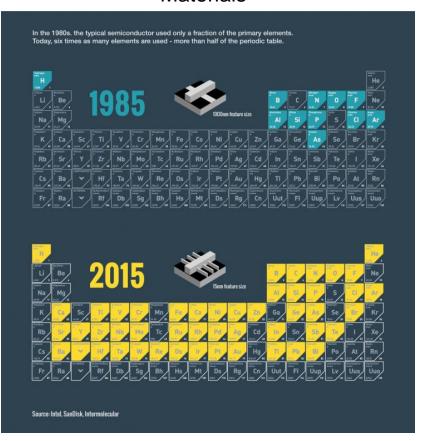
#### Bert Jan Offrein



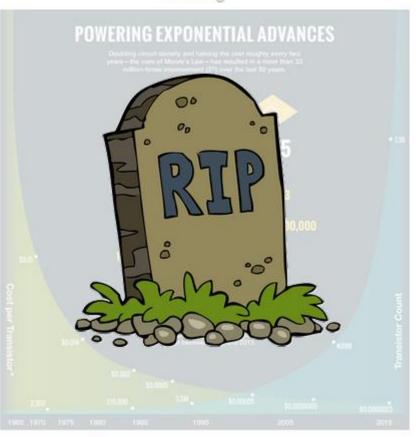


#### Three pillars for Si technology

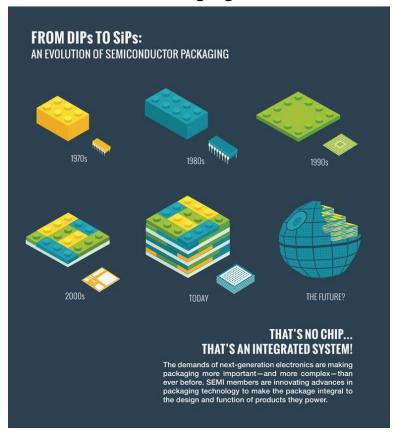
#### Materials



#### Scaling



#### Packaging

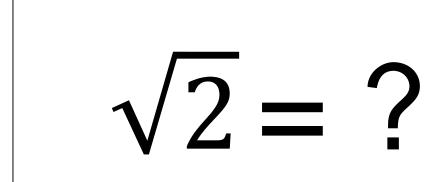


www.semi.org



### **Experiment: "Human Brain vs. Computer"**

**Task 1: Mathematics** 



**Task 2: Image recognition** 



Traditional silicon scaling ended New types of problems gain interest



**Explore new functionalities, More than Moore Explore new computing paradigms** 

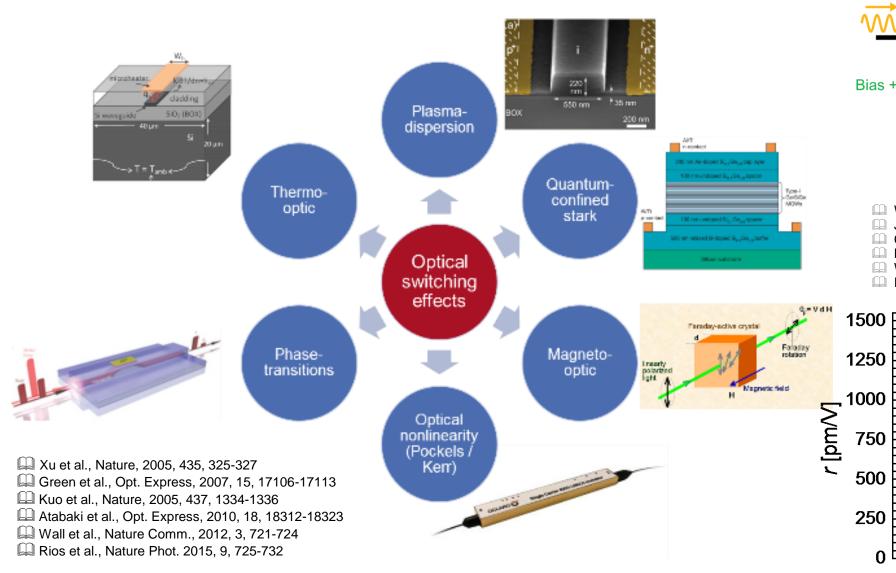


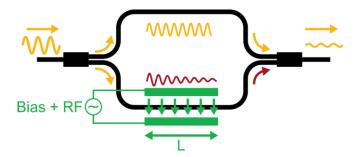
#### Outline

- Facilitate traditional scaling Optical interconnects
  - CMOS Silicon Photonics
    - Pockels modulators, integrating BaTiO<sub>3</sub>
- New computing paradigms Neuromorphic computing
  - Dedicated hardware for neural networks
    - Photonic Synaptic Processor
- Conclusions

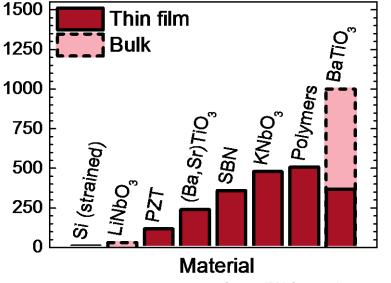


#### Integrated silicon photonics: modulators





- Wessels, Annu. Rev. Mater. Res., 37, 659-679 (2007)
- Jacobsen, Nature, 441, 199-202 (2006)
- Chmielak et al., Opt. Express, 19, 17212-1721 (2011)
- Bernasconi et al., J. Appl. Phys., 78, 2651–2658 (1995)
- Warusawithana, Science, 324 (2009)
- Petraru et al., Appl. Phys. Lett., 81 (2002)



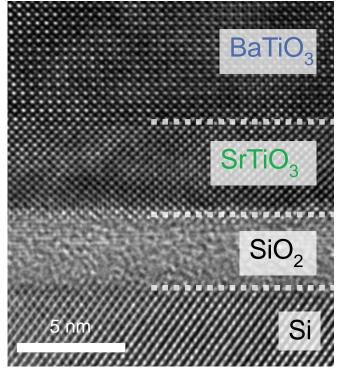


#### Barium titanate on silicon

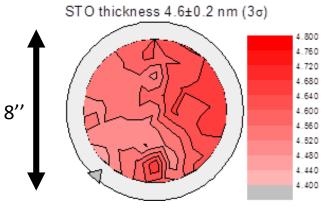
- Molecular beam epitaxy (MBE) or other (PVD, PLD, CVD)
- BaTiO<sub>3</sub> deposition on SrTiO<sub>3</sub> / Si templates
  - Tetragonal crystal structure
  - -Thickness dependant polarization
- Availability on 200mm

SrTiO

Si



Abel et al., Nanotechnology 2013, 24, 285701

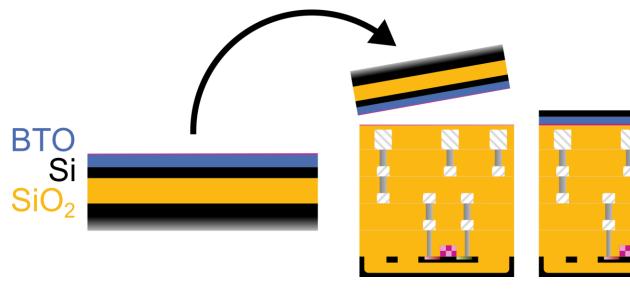


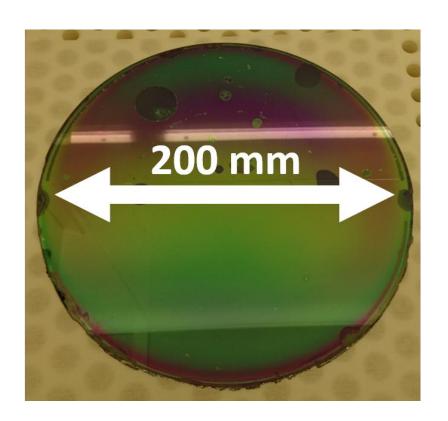
Thickness variations of the 4 nm thick film across the wafer



#### BaTiO3 integration

- Back-end-of-line integration
  - Direct epitaxy not possible on interlayer dielectric
- Transfer by wafer bonding
  - Back-end-of-line compatible
  - Thermal budget <400°C</p>

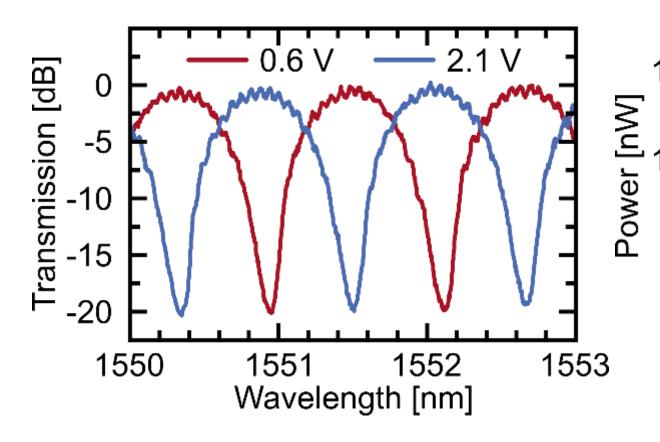


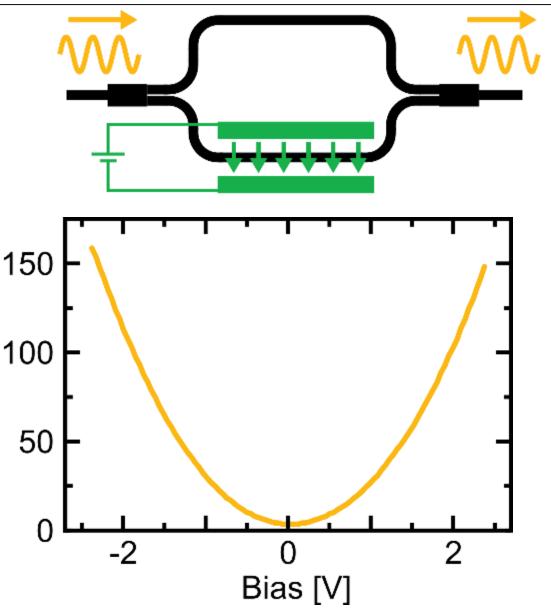




#### Active devices : DC characterization

- Voltage induced phase shift
- Very low DC power



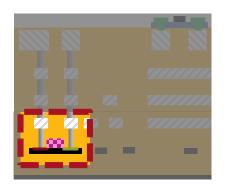


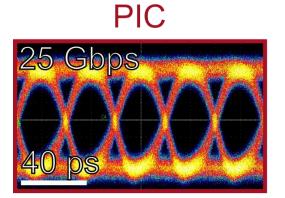
F. Eltes et al., IEDM Tech. Dogest 2017

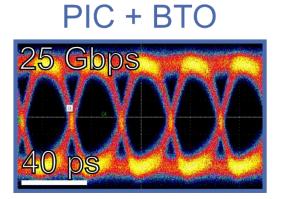


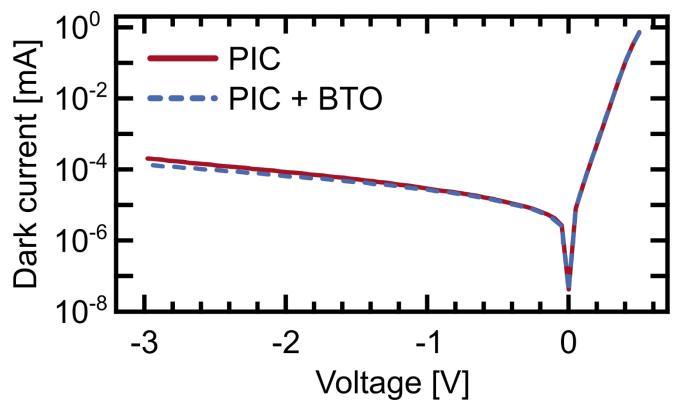
#### Impact on FEOL components

No degradation of Ge photo diodes









Eltes et al., IEDM, 2017



#### Benchmark

Principle	Carrier modulation			Pockels
Structure	p-n	MOS	EAM	
Material	Si <sup>1</sup>	Si <sup>2</sup>	Ge <sup>3</sup>	BTO <sup>6</sup>
$V_{\pi}L$ [V·cm]	2.8	0.2	-	0.3
$V_{\pi}L\alpha$ [V·dB]	27	13	-	1.7
BW [GHz]	40	-	>50	2/20
Integration	+	+	+	+
Phase modulation only	-	-	-	+

#### Pursuing applications in

- High-speed modulators
- Ultra-low optical device tuning (pW)
- Cryogenic eo modulators for optical interfacing to quantum computers
- Non-volatile optical weights in photonic neuromorphic systems



#### Outline

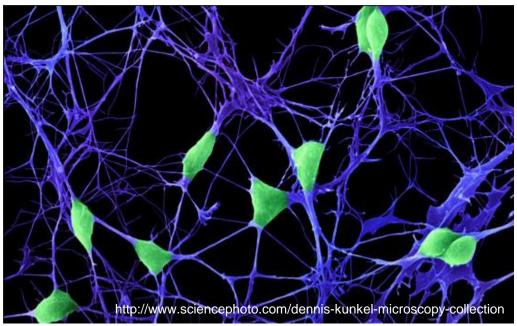
- Facilitate traditional scaling- Optical interconnects
  - CMOS Silicon Photonics
    - Pockels modulators, integrating BaTiO<sub>3</sub>
    - Embedded lasers and detectors, integrating III-V stacks
- New computing paradigms Neuromorphic computing
  - Dedicated hardware for neural networks
    - Resistive Synaptic Processor
    - Photonic Synaptic Processor

Conclusions



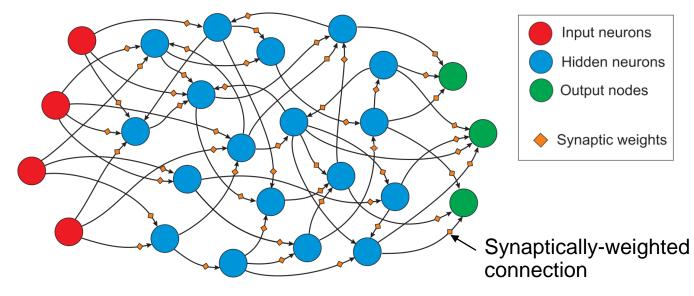
## **Neuromorphic Computing**

#### Brain at neural network level



# Neural Networking

#### Complex model of brain-like neural network



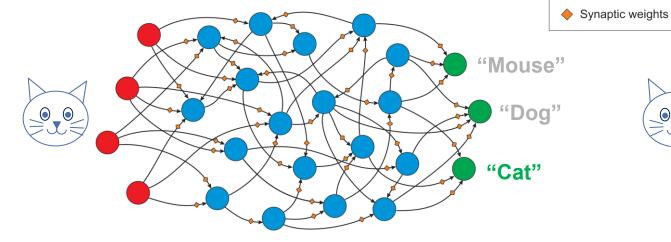
This brain model is too complex to be fully and precisely modelled



Breakthrough in implementation and applicability of neuromorphic computing came with the concept of using simplified Artificial Neural Networks (ANNs)



# Brain inspired computing: Brain-like Neural network:



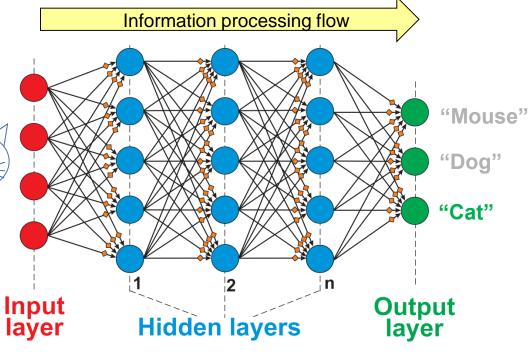


Input neurons

Hidden neurons
Output nodes

- Omni-directional signal flow
- A-synchronous pulse signals
- Information encoded in signal timing
- → Difficult to implement efficiently on standard computer hardware



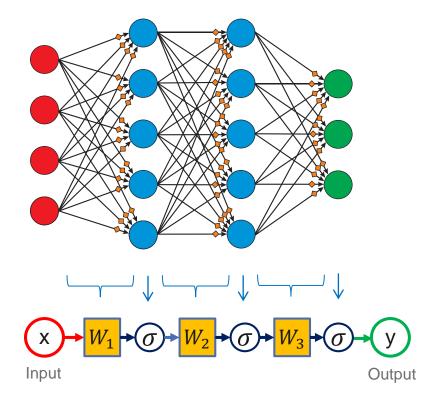


- Feed-forward sequential processing
- Information encoded in signal amplitude
- Neuron activation: Accumulate + Threshold
- Training: Backpropagation Algorithm



# Training: Backpropagation algorithm

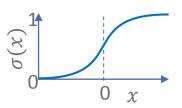
#### **Neural net as chain of vector operations:**



→ : Signal vector

 $\frac{W_n}{W_n}$ : Synaptic weight matrix

(c): Per-element neural activation function (sigmoid)



#### **Backpropagation algorithm:**

For many training cases **x** with target response **t**:

Forward Propagate:

$$X \xrightarrow{X_1} W_1 \xrightarrow{} \emptyset \xrightarrow{} W_2 \xrightarrow{} \emptyset \xrightarrow{} W_3 \xrightarrow{} \emptyset \xrightarrow{} V$$

2. Determine output error:

$$(y-t)^2$$

3. Backward Propagate: Determine neuron input influence  $\delta$  on error **E**:

$$\times W_1^T \leftarrow \sigma' \leftarrow W_2^T \leftarrow \sigma' \leftarrow W_3^T \leftarrow \sigma' \leftarrow E$$

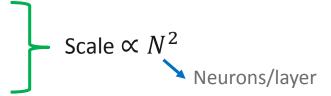
4. Adjust the active weights, proportional to their influence on the error:  $\Delta W = -\eta \ x \otimes \delta$ 



# Efficient training of Deep Artificial Neural Networks:

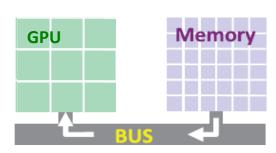
#### **Training by Backpropagation Method:**

- Processing dominated by many large matrix operations
  - Forward Propagation:  $W_{1,2...}$
  - Backward Propagation:  $W_{1,2..}^T$
  - Weight Update:  $\Delta W_{1,2...}$



#### Inefficient on standard Von Neumann systems:

- (Mostly) Serial processing
- Low computation to IO ratio → Memory bottleneck



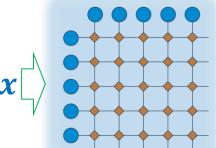
#### For fast and efficient neural network data processing:

- Fully parallel processing
- Tight integration of processing and memory
- Analog signal processing



- Electrica
- Optical





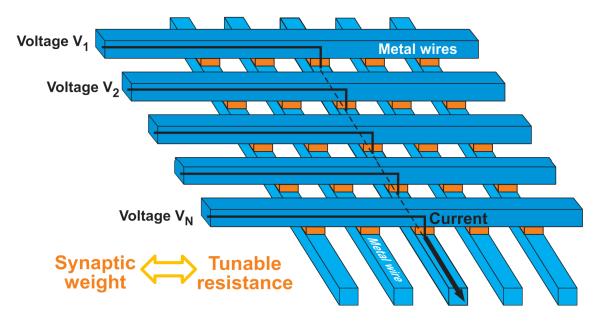
G. W. Burr et al., "Tech. Dig. - Int. Electron Devices Meet. IEDM, vol. 2016–Febru, no. 408, p. 4.4.1-4.4.4, 2016.

<sup>☐</sup> T. Gokmen and Y. Vlasov, Front. Neurosci., vol. 10, no. JUL, pp. 1–13, 2016.



# Analog crossbar arrays:

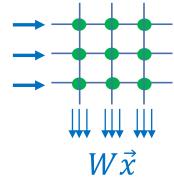
Electrical crossbar array:



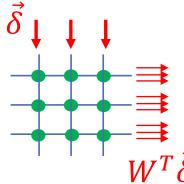
- Weight update: proportional to signals on row and column
  - Symmetric increase and decrease of weight
  - ~1000 analog levels required
- Physical challenge: Identify material systems that meet these requirements



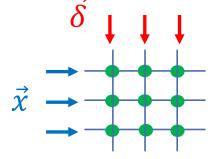
**Forward** propagation:



Backward propagation:



Weight update:



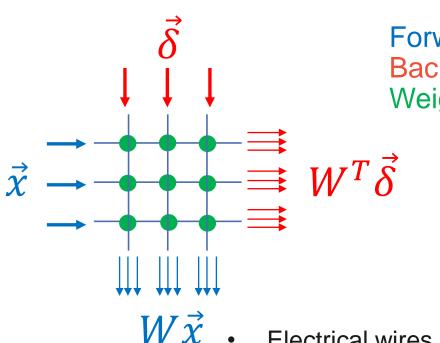
 $\Delta w_{ij} \equiv \eta_{ij} x_{ij} \delta_{ij}$ 



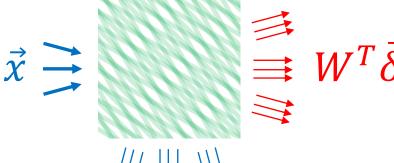
#### Photonic crossbar unit - operating principle

#### **Electrical crossbar**

#### Photonic crossbar



Forward propagation **Backward propagation** Weights



 $W\vec{x}$ 

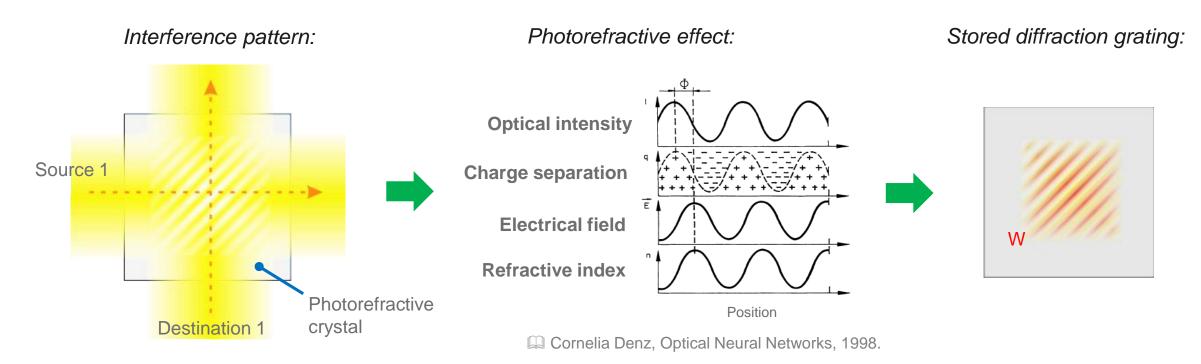
- **Electrical wires**
- Local weights
- Resistance tuning

- Planar waveguiding
- Distributed weights
- Refractive index tuning

Writable photorefractive gratings provide the same functionality as the tunable resistive elements in a crossbar unit



# Optical crossbar arrays: Holographic storage and signal processing Weight Storage:



#### Synaptic weights are stored as refractive index gratings in a photorefractive material:

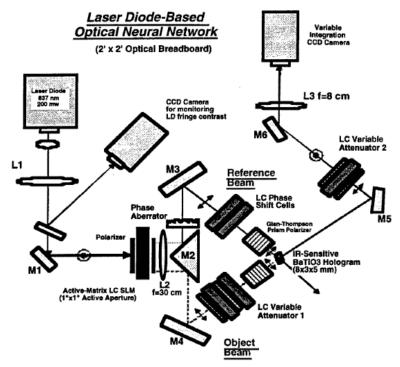
- Grating are written by two interfering optical beams
- Photorefractive effect: Optically active electron traps + Pockels effect → refractive index grating
- Linear and symmetric process



# Optical crossbar arrays: Integrated Solution

#### **Concept demonstrated in bulk optics**

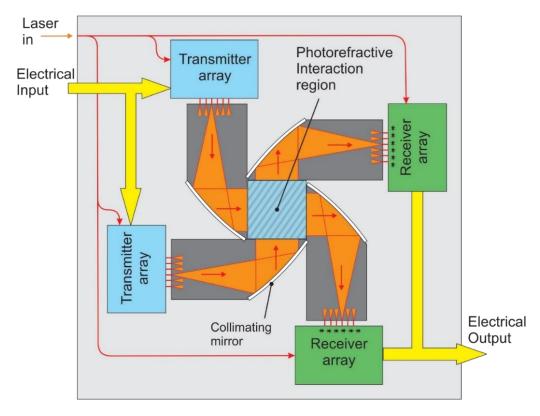
- Backpropagation training of neural networks with hidden layers
- Large setup, slow electro-optics, stability issues



Yuri Owechko and Bernard H. Soffer, "Holographic neurocomputer utilizing laser diode light source", 1995

#### **Our approach: Miniaturize using Integrated Optics**

- Electro-optic conversion and beam shaping optics on a silicon photonics chip
- Memory: Photorefractive thin film on silicon



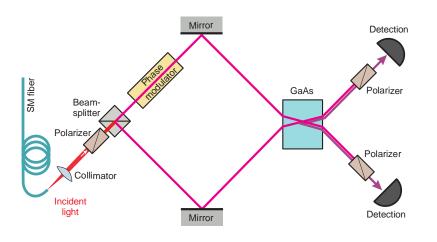


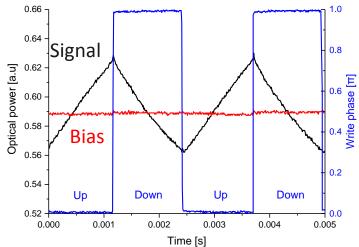
# Photonic weight processing unit: Building blocks

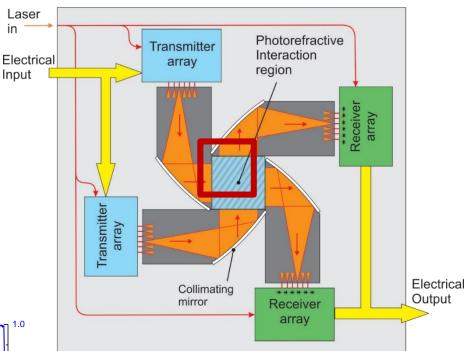
#### **Photorefractive interaction region:**

- Stores synaptic weights as refractive index gratings
- Photorefractive material: Semi-Insulating GaAs
  - Matches Si-Photonics wavelength range
  - Compatible with III-V on Silicon processes

#### **Two-wave mixing in bulk GaAs crystal** ≈ single synapse:







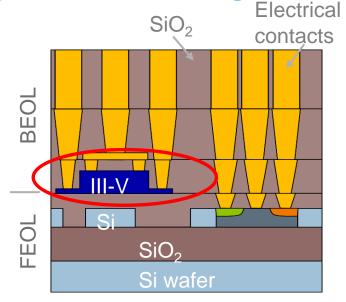
- Low asymmetry
- High dynamic range
- Bipolar weight storage
- To be confirmed in thin film

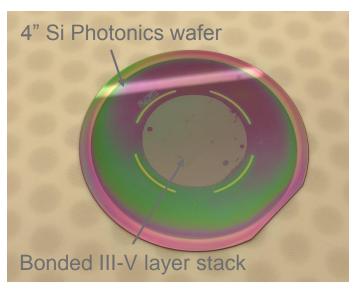


# Photonic weight processing unit: Building blocks

#### **Integration of the photorefractive layer:**

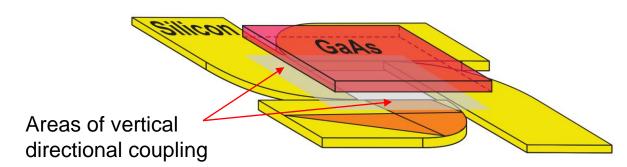
- Bonding technology as demonstrated for other III-V on Si projects:
  - Gain layers for integrated light sources
- Oxide bonding to Silicon-photonics stack



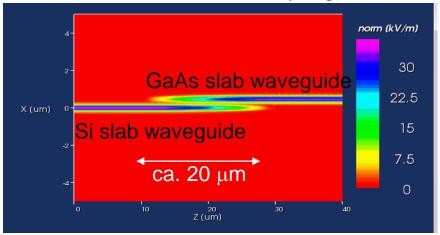


M. Seifried et al., "Monolithically Integrated CMOS-Compatible III–V on Silicon Lasers" doi: 10.1109/JSTQE.2018.2832654.

 Vertical directional coupling for efficient coupling of light between Si-photonic and GaAs layers



#### Vertical directional coupling





#### Summary

- Silicon technology remains the basis for computing devices
  - Leverage existing processes, infrastructure and know-how
  - Continuous extending of materials and function
- Silicon Photonics is currently becoming a major driver for employing optical interconnects
  - Intra- and inter-datacenter communication
  - Integration is functions is a must for cost and assembly reasons
- New computing paradigms Neuromorphic computing provides a path to handle unstructured data
  - Analog signal processing in crossbar arrays
  - Parallel processing of key algorithms in neural networks
  - Electrical and optical implementations



#### Acknowledgments

#### **IBM Research – Zurich, Switzerland**

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